L Number	Hits	Search Text	DB	Time stamp
-	2	("20020084747").PN.	USPAT;	2003/07/31
			US-PGPUB;	14:41
			JPO;	
			DERWENT	
-	5653	(insulator insulating) and electrode and (transparent	USPAT;	2003/07/31
		ITO) and reflecting	US-PGPUB;	13:31
			JPO;	10.01
			DERWENT	
-	1457	(TFT or (thin adj film adj transistor)) and (insulator	USPAT;	2003/07/31
	1457	insulating) and electrode and (transparent ITO) and	US-PGPUB;	13:32
		, , ,	JPO;	13.32
		reflecting		
		50440404100	DERWENT	0000107101
-	44	5341012.URPN.	USPAT	2003/07/31
				14:38
-	1	("20030083544").PN.	USPAT;	2003/07/31
			U5-PGPUB;	16:05
		,	JPO;	
			DERWENT	
-	7	(("6583456") or ("6407418") or ("6593689") or	USPAT;	2003/07/31
		("20020158588")).PN.	US-PGPUB;	16:24
	:		JPO;	
			DERWENT	
-	3	("6034406" "6051857" "6069376").PN.	USPAT	2003/07/31
	-	,		16:16
-	34	5408345.URPN.	USPAT	2003/07/31
	•			16:23
_	2299	(313/506,499,503,504). <i>CC</i> LS.	USPAT;	2003/07/31
_	22//	(010/ 000, 177,000,00 1).0000.	US-PGPUB;	16:25
			JPO;	10.23
			DERWENT	
	-7 4	(/313 /504 400 503 504) (CLC) === //TET === //L': - !!		2002/07/21
-	71	((313/506,499,503,504).CCLS.) and (TFT or (thin adj	USPAT;	2003/07/31
		film adj transistor)) and (transparent ITO) and	US-PGPUB;	16:26
		(reflecting reflect)	JPO;	
			DERWENT	
-	8	("5643826" "5711824" "5834893" "5882761"	USPAT	2003/08/01
		"5891264" "5923962" "6056614"		09:47
		"6242290").PN.		
-	25	5834893.URPN.	USPAT	2003/08/01
				09:49
-	8	("5643826" "5711824" "5834893" "5882761"	USPAT	2003/08/01
		"5891264" "5923962" "6056614"		09:57
		"6242290").PN.		
-	15	("4356429" "4670689" "4908603" "4950950"	USPAT	2003/08/01
		"5122711" "5291098" "5294870" "5427858"		10:32
		"5505985" "5529853" "5552678" "5663573"		
		"5674597" "5674635" "5681664").PN.		
-	7	("3172862" "3173050" "3227656" "3530325"	USPAT	2003/08/01
	' ,	"3621321" "3995299" "4164431").PN.	3317.1	10:33
_	94	5616506.URPN.	USPAT	2003/08/01 11:15
-	フサ	JULUJUU.URFIN.	UJFAI	F003\00\01 11:13

-	170	(TFT or (thin adj film adj transistor)) and (insulator	USPAT;	2003/08/01
		insulating) and electrode and (transparent ITO) and reflecting and luminous	US-PGPUB; JPO; DERWENT	11:39
-	63	((TFT or (thin adj film adj transistor)) and (insulator	USPAT;	2003/08/01
		insulating) and electrode and (transparent ITO) and reflecting and luminous) and (gate same (transparent ITO))	US-PGPUB; JPO; DERWENT	11:39
•	3	((TFT or (thin adj film adj transistor)) and (insulator insulating) and electrode and (transparent ITO) and	USPAT; US-PGPUB;	2003/08/01 11:39
		reflecting and luminous) and (gate near3 (transparent ITO))	JPO; DERWENT	,